Spin Photovoltaic E ect in Quantum W ires with Rashba

Interaction

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Abstract

W e propose a mechanism for spin polarized photocurrent generation in quantum wires. The e ect is due to the combined e ect of Rashba spin-orbit interaction, external magnetic eld and m icrowave radiation. The tim e-independent interactions in the wire give rise to a spectrum asymm etry in k-space. The m icrowave radiation induces transitions between spin-splitted subbands, and, due to the peculiar energy dispersion relation, charge and spin currents are generated at zero bias voltage. W e demonstrate that the generation of pure spin currents is possible under an appropriate choice of external control param eters.

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The Rashba spin-orbit interaction (SO I) [1] in transport and equilibrium phenomena [2, 3, 4, 5, 6, 7, 8] plays a central role in the fast growing elds of spintronics and quantum computation [9]. In particular, it was recently discovered that the joint action of the Rashba SO I and in-plane magnetic eld on electrons con ned in 1D quantum wires (QW) results in unique properties [2, 3, 4]. Several useful applications based on these properties were proposed, including a scheme for measuring nuclear spin polarization [2] and a spin-liter [3].

In this letter we theoretically investigate the e ect of a microwave radiation in a QW with Rashba SOI and an in-plane magnetic eld. This setup was stimulated by recent experiments on the modi cations of the Hall e ect in the presence of a microwave eld [10]. We will show below that spin and charge photocurrents can be generated in microwave irradiated QW s (spin photovoltaic e ect). The e ect originates in the broken symmetry of QW subbands caused by the interplay of SOI and constant magnetic eld. We emphasize that this mechanism is based primarily on spin degrees of freedom in contrast to other mechanisms of photovoltaic e ect considered before (see, e.g., Ref. [11]) and diers from the optical spin current generation [12].

In our model a ballistic QW of length L is connected to two electron reservoirs having equal chemical potentials . This geometry is realized, for instance, in a QW created by a split gate technique in a two-dimensional electron gas (2DEG). For the sake of simplicity we assume that only the QW region is irradiated by the microwave eld. W ithout microwave radiation the currents in QW from the left to the right reservoir and from the right to the left reservoir balance each other so that the total current through the QW is zero. The microwave radiation induces transitions between spin-splitted subbands. The electron wave vector k is conserved in such transitions, how ever, in the presence of SO I the electron velocity

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is not simply proportional to k. The direction of the electron velocity, in speci c intervals of k, can be reversed after the transition. The intersubband transition rate, due to the asymmetry of QW subbands, is dierent for left-right-moving electrons, and produces a net charge current. The spin current is also in uenced by the microwave eld, since spin ips occur in these transitions.

We consider a QW in the x direction created via a lateral con nement (in y direction) of a 2D EG in the (x, y) plane. The H am iltonian for the conduction electrons in the QW in the presence of the m icrow ave radiation can be written in the form [2, 3, 4],

$$H = \frac{p^2}{2m} + V(y) \quad i \quad y \frac{\theta}{\theta x} + \frac{g}{2} R(t) + U(z;t):$$
(1)

We assume the microwave eld propagating in the (x, y) plane and we x the electric eld component in z direction. In Eq. (1), p is the momentum of the electron, m is the electron e ective mass, V (y) is the lateral connement potential due to the gates, is the SO I constant, ~ is the vector of Pauli matrices, $_{\rm B}$ and g are the Bohr magneton and e ective g-factor, and U (z;t) is the potential due to the electric eld component of the radiation. $B = B_0 + B_1 \cos(!t)$, where B_0 is the in-plane constant magnetic eld and B_1 is the magnetic eld component of the microwave radiation, and ! is the radiation frequency. U (z;t) can be neglected because it does not couple spin-splitted subbands. The third term in (1) represents the Rashba SO I for an electron moving in the x-direction. We assume that the elects of the

D resselhaus SO I can be neglected [13].

At $B_1 = 0$, the solutions of the Schrödinger equation can be written in the form

$$l_{i}(k) = \frac{e^{ikx}}{\frac{p}{2}} e^{i'} l_{1}(y); \qquad (2)$$

where ' = arctan $[B_{0y}=B_{0x} 2 k=(g_B B_{0x})]$ and (y) is the wave function of the transverse m odes (due to the con nem ent potential V (y)). The eigenvalue problem can be solved

to obtain

$$E_{1;} (k) = \frac{E_{2}^{2}}{E}\tilde{k}^{2} + E_{1}^{tr} \quad E_{Z} \quad 1 + \frac{2\tilde{k}B_{0;y}}{B_{0}} + \tilde{k}^{2}:$$
(3)

Here, $K = k = E_z$, $E = 2m^{2}$, $E_z = g_B B_0 = 2$, and E_1^{tr} is the 1-th eigenvalue of V (y). A ssum ing the parabolic connem ent potential in the y-direction, we have $E_1^{tr} = -!_0$ (l+ 1=2).

The energy spectrum corresponding to Eq. (3) is illustrated in Fig. 1, for the two spinsplit subbands characterized by l = 0 and B_0 directed at =4 with respect to the x-axis in (x, y) plane. Notice that the down-splitted subband has a clearly de ned asymmetry. This subband features several local extrem a, namely, two minim a and one maximum. The energy branches avoid the crossing and form a local gap. The expectation values of spin polarization in the states (2) are h $j_x j i = \cos(r/k)$) and h $j_y j i = \sin(r/k)$). W hile the external magnetic ekd realigns the electron spins in the gap region, far from this region the spins are polarized in y direction by the Rashba SO I (Fig. 1). The velocity of an electron is determined by v (k) = QE = -Qk. Denoting by k_{+}^{min} , $k^{min;l}$, k^{max} , $k^{min;2}$ the positions of the local extrem a of $E_{1;t}$ and $E_{1;}$, we not from Eq. (3) that $v_{+} < 0$ for $k < k_{+}^{min}$, $v_{+} > 0$ for $k > k_{+}^{min}$, v < 0 for $k < k^{min;l}$ and $k^{max} < k < k^{min;2}$, v > 0 for $k^{min;l} < k < k^{max}$ and $k > k^{min;2}$. Generally, $k_{+}^{min} \in k^{max}$. Thus, there are 2 intervals of k when the directions of v (k) and v, (k) are opposite.

N ext we consider transitions generated by the time-dependent magnetic eld $B_1 \cos(!t)$. It can be shown that the transition rate di ers from zero only for transitions between subbands characterized by the same number lw ith conservation of k (examples of such vertical transitions are presented in Fig. 1). We calculate the transition rate using the expression

$$W = \frac{2}{2} + \frac{g_{B}}{2} \sim B_{1}^{2} \qquad (E_{l;+} E_{l;} \sim !): \qquad (4)$$

It follows from Eq. (4) that the transition rate depends on the relative orientation of the spin

polarization in a state k and the direction of \mathcal{B}_1 . This property allows to use the direction of the oscillating magnetic eld as an additional parameter that controls spin and charge currents in the QW.

In order to take into account the e ect of the time-dependent magnetic eld on transport properties of the QW we solve the Boltzmann equations

$$v(k)\frac{\partial f}{\partial x} = Wf(1f) Wf(1f);$$
 (5)

for the distribution functions f (k;x). A samming that the chemical potential is below the minimum of E₊ (k) and a low temperature, we supplement Eqs. (5) by the following boundary conditions: for v (k) > 0, f (x = 0) = f(); for v (k) < 0, f (x = L) = f(); for v₊ (k) > 0, f₊ (x = 0) = 0; for v₊ (k) < 0, f₊ (x = L) = 0, where f() is the Ferm i function. The solution of linearized Eqs. (5) with the speci ed above boundary conditions was found analytically. We calculate the current as $[14] I = \frac{e}{h}^{P} = \frac{R_{1}}{1} v$ (k) f (k)dk: We found that the transitions conserving the velocity direction do not change the charge current. The current as a function of the excitation frequency is shown in Fig. 2 and has a two-peak structure. The rst peak in this structure corresponds to transitions between the states with k near $k^{m ax}$, the second peak corresponds to transitions between states with k near $k^{m in/2}$. The direction and am plitude of the charge photocurrent shows a signi cant dependence on the direction of B₁, especially in the rst peak region, because the spin structure in this region is strongly a ected by the magnetic eld direction.

As electrons carry spin as well as charge, the time-dependent magnetic eld also inuences the spin current through the wire. The spin current can be de ned as the transport of electron spins in real space. When the electron transport is con ned to one dimension, the spin current is a vector. Its components can be calculated using $I^{s} = \frac{1}{h}^{P} = \frac{R_{1}}{h}$ h j j iv (k)f (k)dk where = (x;y;z). Fig. 3 shows the x and y components of the spin current ($I_{z}^{s} = 0$) calculated for two di erent values of the chemical potential . The main features of the spin current are: (i) the spin current is coordinate-dependent; (ii) transitions conserving the direction of the electron velocity contribute also to the spin current; (iii) generation of a pure spin current (w ithout a charge current) occurs for transitions with v (k)v₊ (k) > 0. The spin current components calculated at = 0 have a complex dependence on !. At = 0.3E the role of di erent transitions can be more easily understood. W ith increase of !, we rst observe excitations with v (k)v₊ (k) > 0. The insets in Fig. 3 show that the rst type of transitions leads to changes of spin current at x = 1 only. The asymmetry of the spin current components at x = 0 and x = L, while the spin current components at x = 0 and x = L is a signature of pure spin currents in the system .

W e now discuss the conditions for an experim ental observation of this spin photovoltaic e ect. First, a QW should be fabricated from a structure with large R ashba SO I.A promising candidate are InAs based sem iconductor heterostructures, which have a relatively large

[15]. The characteristic energy of the SOI for these structures (= 4.5 10 ¹¹eVm, m = 0.036m_e [16]) is E = 1.9m eV. Assuming $E_z = 0.1E$ and taking g = 6 [17] we obtain $B_0 = 1.1T$. Second, we note that extremely low temperatures are not required for experimental observation of the spin photovoltaic elect. From the condition k_BT . E, E_z we estimate T. 2K. Finally, the condition that $B_1 \in 0$ only in the QW region was used only for convenience. In a real experiment the whole system (QW and leads) is subjected to a nite B_1 . The elect of the leads depends on the particular system studied, but should not considerably a lect the scheme proposed here, especially if there is no appreciable SOI in the leads.

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Figure captions.

Figure 1. (Coloronline) Energy dispersion E_0 ; (k) (with respect to E_0^{tr}) for $E_z = 0.1E$ and $B_0 = (B_0 = 2; B_0 = 2; 0)$. Spin orientation is illustrated by arrows (h_xi is plotted along K, h_yi is plotted along E, and h_zi = 0).

Figure 2. (Color online) Current through QW as a function of the excitation frequency !. is the in-plane angle between B_1 and x axis, = 0, T = 0.

Figure 3. (Color online) Spin current components as a function of the excitation frequency !, = 0, T = 0. The region of pure spin currents is to the right of the vertical dashed line. Insets: spin current components at = 0.3.

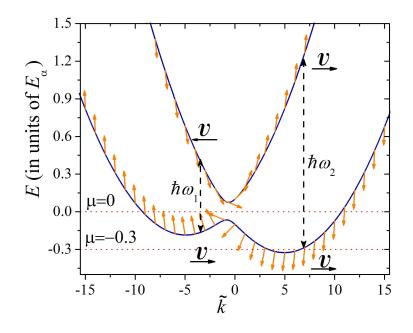


FIG.1:

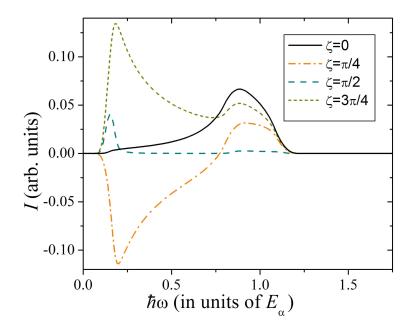


FIG.2:

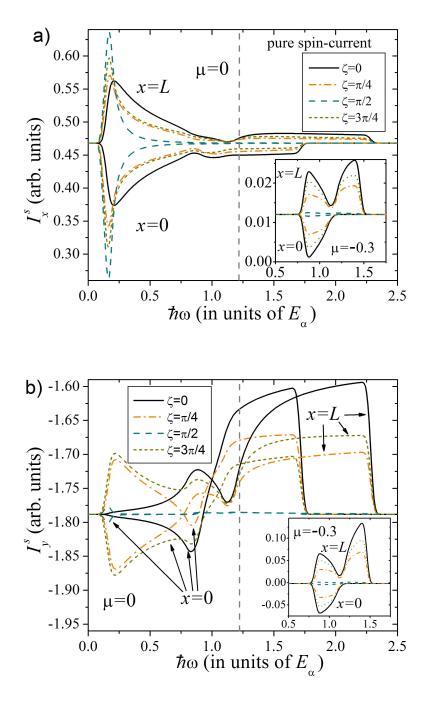


FIG.3: